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03500.101486.

PATENT APPLICATION

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Mn re Application of:

TOMONARI NAKAYAMA, et al.

Application No.: 10/559,799
Int'l. Filing Date: June 9, 2005

For: FIELD EFFECT TRANSISTOR
AND PRODUCTION PROCESS
THEREOF

November 3, 2006

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §\$ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the enclosed Form PTO-1449. Copies of the listed documents, other than the U.S. patent documents, are enclosed.

Japan 2004-63977, Japan 2004-63975, Japan 2004-128469, Japan 2004-6700, Japan 2004-146796, U.S. Patent No. 6,861,377, and U.S. Publication No. 2004/0131782 were cited in the International Search Report and/or Written Opinion which issued in the corresponding international application. A copy of the International Search Report and a copy of the Written Opinion are enclosed.

The following documents are discussed at the following pages of the specification:

	Page(s)
Documents 1 Phys. Lett. Vol. 53, No. 3,	2
A. Assadi, et al., Appl. Phys. Lett., Vol. 53, No. 3, July 18, 1988	2 .
H. Fuchigami, et al., Appl. Phys. Lett., Vol. 63, No. 10, September 6, 1993	-
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Japan 10-190001	4
Janos Veres, et al., Advanced Functional Materials, Vol. 13,	
No. 3, March 2003	5
Zhenan Bao, et al., Chem. Mater., Vol. 9, No. 6, 1997	

An English-language abstract for each of the Japanese documents listed on the Form PTO-1449 is enclosed.

According to a commercial database, U.S. Patent No. 6,861,377 is in the same patent family as Japan 2004-6700, U.S. Patent 6,107,117 is in the same patent family as Japan 10-190001, and U.S. Publication No. 2004/0131782 is in the same patent family as Japan 2004-146796.

This Information Disclosure Statement is being filed before the issuance of a first Office Action on the merits. Therefore, no fee under 37 C.F.R. § 1.97(c)(2) is believed due. Nevertheless, the Commissioner may charge Deposit Account No. 06-1205, should any fee be due for filing this paper.

EFS-Web Receipt date: 11/06/2006

Applicants request that the above information be considered by the Examiner and that a copy of the enclosed Form PTO-1449 be initialed and returned indicating that such information has been considered.

Applicants' undersigned attorney may be reached in our Costa Mesa,

California office at (714) 540-8700. All correspondence should continue to be directed to our below-listed address.

Respectfully submitted,

Damond E. Vadnais Attorney for Applicants Registration No.: 52,310

FITZPATRICK, CELLA, HARPER & SCINTO 30 Rockefeller Plaza New York, New York 10112-3800 Facsimile: (212) 218-2200 EFS-Web Receipt date: 11/06/2006

ORM PTO 1449 (modified)			ATTY DOCKET NO. 03500.101486.	APPLICATION NO.	APPLICATION NO. 10/559,799			
	EPARTMENT OF COMMERCE IT AND TRADEMARK OFFICE		APPLICANT TOM	ONARI NAKAYA	AMA, et al.			
(Use several sheets if necessary) NOV 0 6 2006		INT'L FILING DATE: June 9, 2005		GROUP 2814				
	18	- 5	U.S. PATENT DOCUMENTS					
EXAMINER	I DOCUMENT	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE		
/B.J./	NUMBER	03/01/05	Hirai, et al.	438	781			
	6,861,377		Bao, et al.	438	99			
/B.J./	6,107,117	08/22/00	Hasei, et al.	427	337			
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			FOREIGN PATENT DOCUMENTS			TRANSLATION		
	DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	YES/NO/ OR ABSTRACT		
/B.J./	NUMBER	05/20/04	Japan			Abstract		
	2004-146796	08/22/06	Japan			Abstract		
/B.J./	2004-128469	02/26/04	Japan	1111		Abstract		
/B.J./	2004-63977		Japan			Abstract		
/B.J./	2004-63975	02/26/04				Abstract		
/B.J./	2004-6700	01/08/04				Abstract		
/B.J./	10-190001	07/21/98	Japan					
•			Two Data B	adjant Pages, Fig.)				
		OTHER DOCUMEN	NT(S) (Including Author, Title, Date, P	tet !bana!	Anni Phys	Lett.		
/B.J./	Vol. 53 No. 3	. July 18, 198	ect mobility of poly(3-h 38, pp. 195-197.					
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/B.J./	H. Fuchigami	H. Fuchigami, et al., "Polythienylenevinylene thin-film transistor with high carrier mobility",						
/B.J./		Janos Veres, et al., "Low-k Insulators as the Choice of Dielectrics in Organic Field-Effect Transistors", Advanced Functional Materials, Vol. 13, No. 3, March 2003, pp. 199-204.						
	/Bilkis Jahan/		DATE CONSIDERED	03/24/2008				

*EXAMINER: Initial if reference considered, whether or not clasion is in conformance with MPEP 600; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Sheet_1_ of __1

Form #61

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